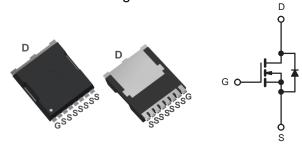


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N-Channel 80 V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	R _{DS(on)} (mΩ) TYP.	I _D (A)	Q _g (TYP.)		
80	2 at V _{GS} = 10 V	150	119 nC		

TOLL Pin Configuration



N-Channel MOSFET

FEATURES

- DT-Trench Power MOSFET
- 100 % $\rm R_g$ and UIS tested

APPLICATIONS

- Power supplies:
 - Uninterruptible power supplies
 - AC/DC switch-mode power supplies
 - Lighting
- Synchronous rectification
- DC/DC converter
- Motor drive switch
- DC/AC inverter
- Battery management

PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V _{DS}	80	V	
Gate-Source Voltage		V _{GS}	± 20		
	T _C = 25 °C		150	٨	
Continuous Drain Current ($T_J = 150 \text{ °C}$)	T _C = 100 °C	– I _D –	133		
Pulsed Drain Current (t = 100 μs)		I _{DM}	600	A	
Avalanche Current	L = 0.1 mH	I _{AS}	145		
Single Avalanche Energy ^a		E _{AS}	1010	mJ	
Maximum Power Dissipation ^a	T _C = 25 °C	P	216	W	
Maximum Power Dissipation ~	$T_{C} = 100 \ ^{\circ}C$	FD FD	84.6 ^b		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient (PCB Mount) ^c	t ≤ 10 s	R _{thJA}	20	°C/W	
Junction-to-Case (Drain)	Steady State	R _{thJC}	0.5	C/W	

Notes

a. Duty cycle \leq 1 %.

b. See SOA curve for voltage derating.

c. When mounted on 1" square PCB (FR4 material).



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SPECIFICATIONS ($T_J = 25 \ ^{\circ}C$,	unless othe	erwise noted)				
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = 250 \mu\text{A}$	80	-	-	v
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	1.5	-	3.5	
Gate-Body Leakage	I _{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V	-	-	± 100	nA
		V_{DS} = 80 V, V_{GS} = 0 V	-	-	1	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS}=64~V,~V_{GS}=0~V,~T_J=85~^\circ C$	-	-	10	μA
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \geq 10 \text{ V}, V_{GS} = 10 \text{ V}$	150	-	-	А
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	-	2	2.6	mΩ
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 10 \text{ V}, I_D = 20 \text{ A}$	-	166	-	S
Dynamic ^b						
Input Capacitance	C _{iss}		-	9878	-	pF
Output Capacitance	C _{oss}	V_{GS} = 0 V, V_{DS} = 40 V, f = 1 MHz	-	3294	-	
Reverse Transfer Capacitance	C _{rss}		-	76	-	
Total Gate Charge ^c	Qg		-	119	-	nC
Gate-Source Charge ^c	Q _{gs}	V_{DS} = 40 V, V_{GS} = 10 V, I_{D} = 20 A	-	42	-	
Gate-Drain Charge ^c	Q _{gd}		-	33	-	
Gate Resistance	R _g	f = 1 MHz	-	2.0	-	Ω
Turn-On Delay Time ^c	t _{d(on)}		-	30	-	
Rise Time ^c	t _r	V_{DD} = 40 V, I _D = 20 A, R _g = 6 Ω V _{GEN} = 10 V	-	48	-	ns
Turn-Off Delay Time ^c	t _{d(off)}		-	59	-	
Fall Time ^c	t _f		-	33	-	
Drain-Source Body Diode Ratings and	Characterist	ics ^b (T _C = 25 °C)				
Continuous Source-Drain Diode Current	۱ _S	T _C = 25 °C	-	-	150	А
Pulsed Current (t = 100 µs)	I _{SM}		-	-	600	А
Forward Voltage ^a	V _{SD}	$I_{F} = 1 \text{ A}, V_{GS} = 0 \text{ V}$	-	-	1	V
Reverse Recovery Time	t _{rr}	l _F = 20 A, di/dt = 100 A/μs	-	105	-	ns
Reverse Recovery Charge	Q _{rr}		-	289	-	nC

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

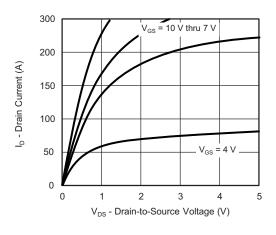
b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

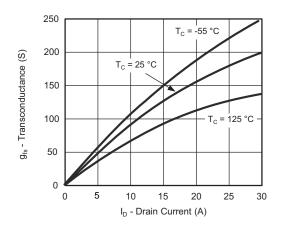
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



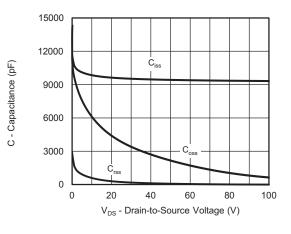
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



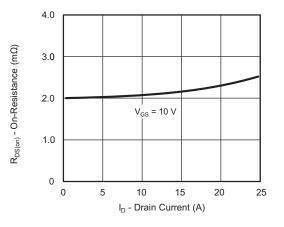
Output Characteristics



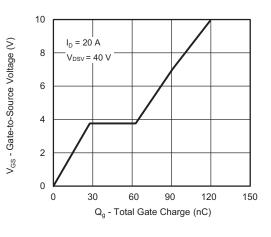
Transconductance



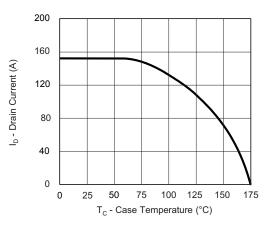
Capacitance



On-Resistance vs. Drain Current



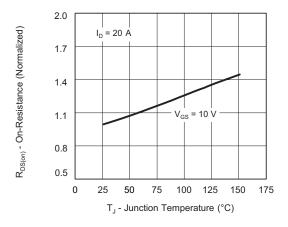
Gate Charge



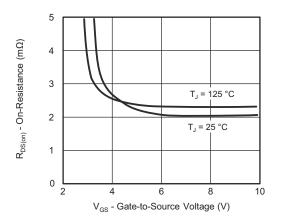
Current De-Rating



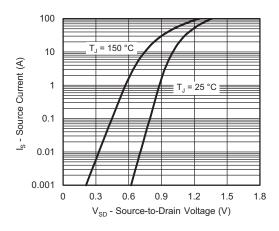
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



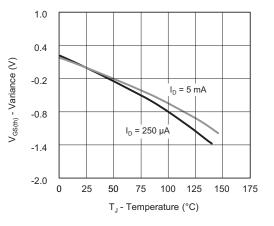
On-Resistance vs. Junction Temperature



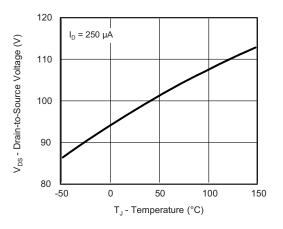
On-Resistance vs. Gate-to-Source Voltage



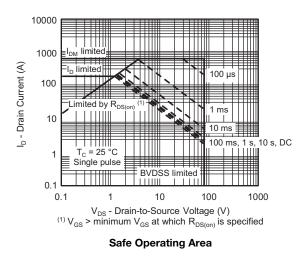
Source Drain Diode Forward Voltage



Threshold Voltage

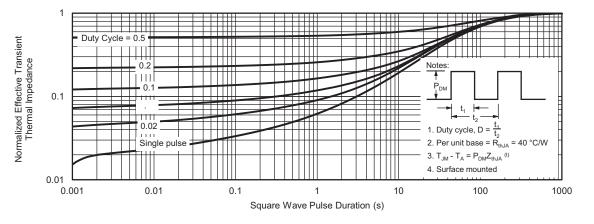


Drain Source Breakdown vs. Junction Temperature





THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



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